



# AK2921

Zero Drift operational amplifiers

## Feature

AK2921 is the dual channel CMOS operational amplifiers which is available to output with very low input offset voltage ( $+/- 1.0\mu V$ ) and near zero input offset drift.

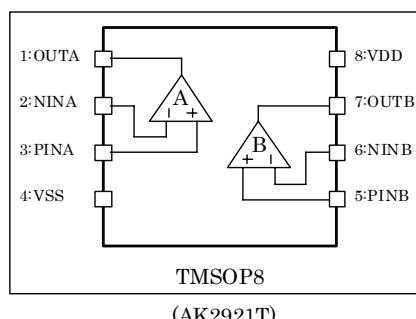
It's operated with very small current consumptions,  $260\mu A$  typ./ch (VDD:5.0V), which is available to operate full swing signals in output.

AK2921 is appropriated to Sensor Pre Amp. applications.

- Low Voltage, Single Supply Operation : 1.6V - 5.5V
- Very Low Input Offset Voltage :  $+/- 1.0\mu V$  typ.
- Near Zero Drift over time and temperature :  $+/- 5.0nV/^{\circ}C$  typ.
- Full Swing Outputs to  $10k\Omega$  Load
- Power Supply Current :  $260\mu A$  typ./ch (VDD: 5.0V, No Load)
- Gain Bandwidth : 0.8MHz typ.
- Package : TMSOP8

Part Name	Channel Number	Package
AK2921T	2	TMSOP8

## Pin Location



<b>Pin Function Descriptions</b>			
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<b>Pin number</b>	<b>Name</b>	<b>I/O note)</b>	<b>Function</b>
1	OUTA	AO	Amplifier A Output
2	NINA	AI	Amplifier A Inverted Input
3	PINA	AI	Amplifier A No Inverted Input
4	VSS	PWR	Power Supply Ground
5	PINB	AI	Amplifier B No Inverted Input
6	NINB	AI	Amplifier B Inverted Input
7	OUTB	AO	Amplifier B Output
8	VDD	PWR	Positive Power Supply

Note)

PWR : Power Supply  
 AI : Analog Input  
 AO : Analog Output

<b>Absolute Maximum Ratings</b>			
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VSS=0V ; Note

<b>Parameter</b>	<b>Symbol</b>	<b>Min</b>	<b>Max</b>	<b>Units</b>
Supply Voltage	VDD	-0.3	6.5	V
Input Voltage	V <sub>TD</sub>	-0.3	VDD + 0.3	V
Input Current	I <sub>IN</sub>	-10	+10	mA
Storage Temperature Range	T <sub>stg</sub>	-55	150	°C

Note : All voltage with respect to ground

## WARNING :

Operational at or beyond these limits may result in permanent damage to the device. Normal operation is not guaranteed at these extremes.

<b>Recommended Operating Conditions</b>						
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<b>Parameter</b>	<b>Symbol</b>	<b>Min.</b>	<b>Typ.</b>	<b>Max.</b>	<b>Units</b>	<b>Conditions</b>
Operationg Temperature Range	T <sub>a</sub>	-40		85	°C	
Supply Voltage	VDD	2.7		5.5	V	
Minimum Gain	A <sub>v</sub>	1			V/V	
Power Supply Current	I <sub>dd1</sub>		0.26	0.6	mA/ch	VDD=5.0V,No Load

Note : When the gain is adjusted to one or less , there is a possibility that operation becomes unstable.

\*We asumes no responsibility for the usage beyond the conditions in this datasheet.

<b>Electrical Characteristics</b>
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DC Characteristics

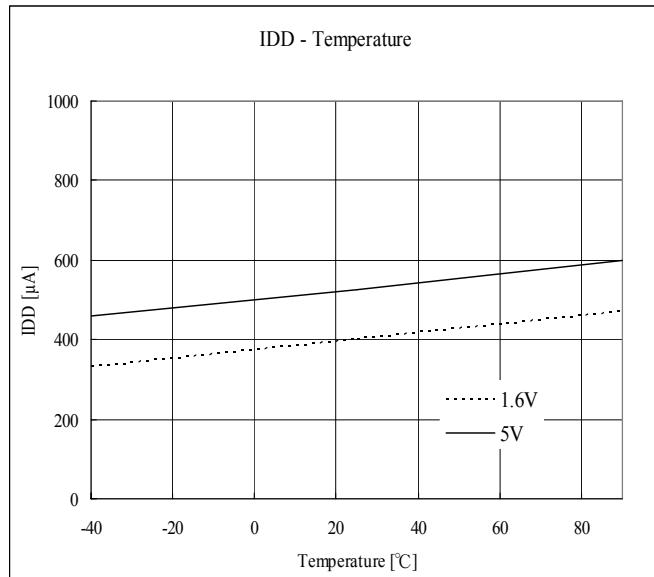
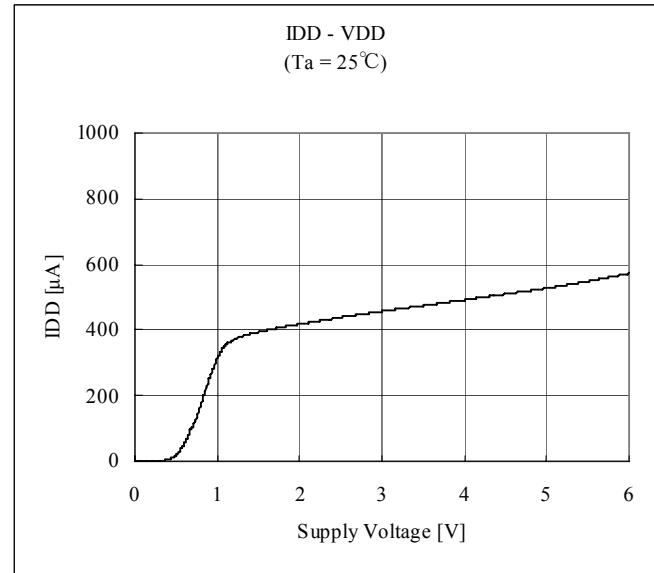
VDD:5V, Ta:-40 to 85°C, unless otherwise noted

Parameter	Min.	Typ.	Max.	Units	Conditions
Input Voltage Offset		+/- 1	+/- 20	µV	
Input Voltage Offset Drift		+/- 5	+/- 100	nV/°C	
Input Bias Current		+/- 20		pA	
Input Common Mode Range		0.0 – VDD-0.2		V	
Output Voltage Swing		0.03 – VDD-0.03		V	RL ≥10kΩ connected to VDD/2
Common Mode Rejection Ratio	100	130		dB	
Power Supply Rejection Ratio	100	120		dB	
Large Signal Voltage Gain	110	130		dB	RL ≥10kΩ connected to VDD/2
Short Circuit Current		+/- 85		mA	
Output Current		+/- 35		mA	

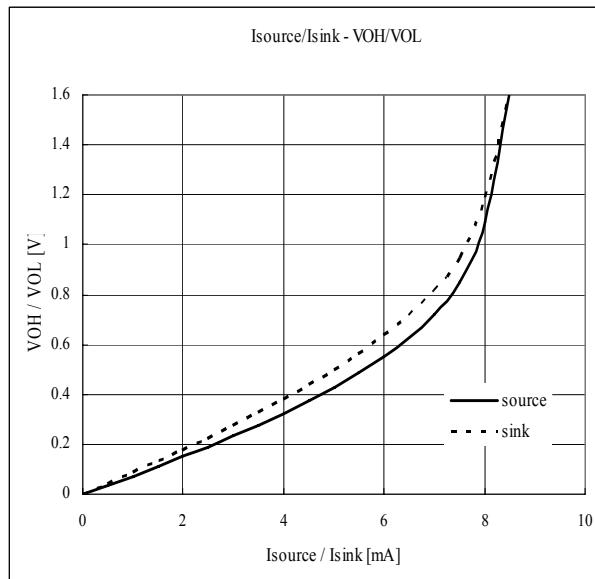
AC Characteristics

VDD:5V, Ta:-40 to 85°C, unless otherwise noted

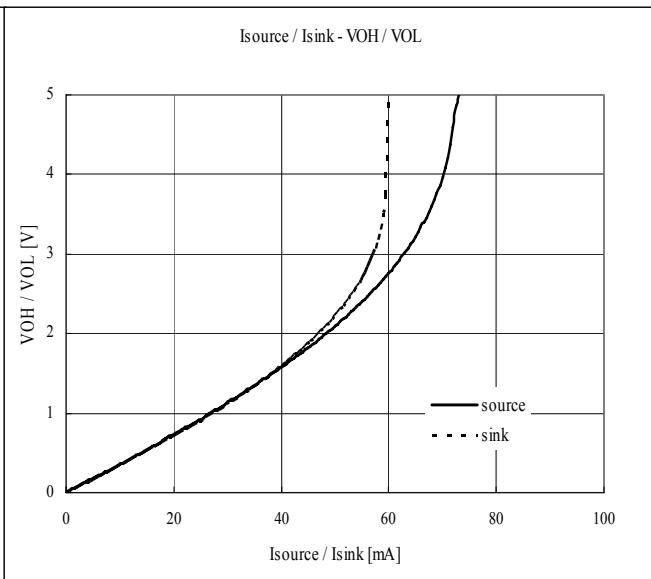
Parameter	Min.	Typ.	Max.	Units	Conditions
Gain Bandwidth		0.8		MHz	Av:1V/V
Slew Rate		1		V/µs	Av:1V/V
Input Voltage Noise		100		nVrms /√Hz	f:1kHz
	0.1 – 10Hz	2.1		µVpp	
	0.1 – 1Hz	0.7		µVpp	
Overload Recovery Time		0.04		msec	Av:50V/V
Input Capacitance	Differential	1.5		pF	
	Common Mode	6		PF	
Maximum Capacitance Loads			150	pF	

**Typical Operating Characteristics** Supply Current vs. Temperature (Vin:1/2VDD) Supply Current vs. Supply Voltage (Vin:1/2VDD)

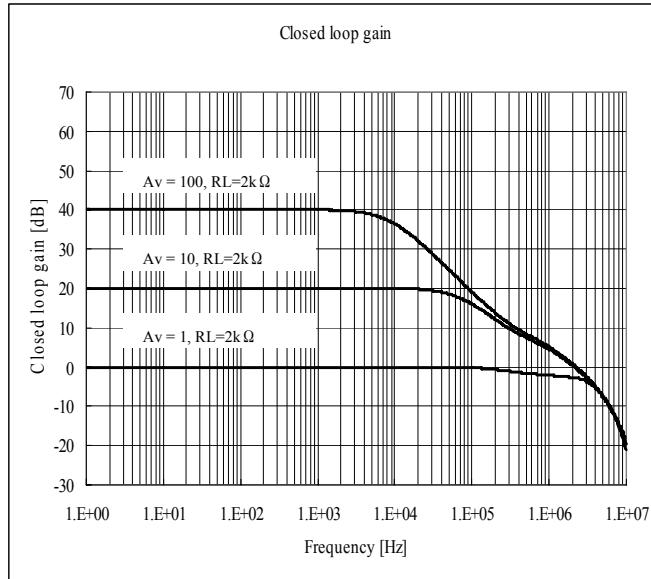
□ Output voltage vs. Load current  
(VDD=1.6V, Ta=25°C)



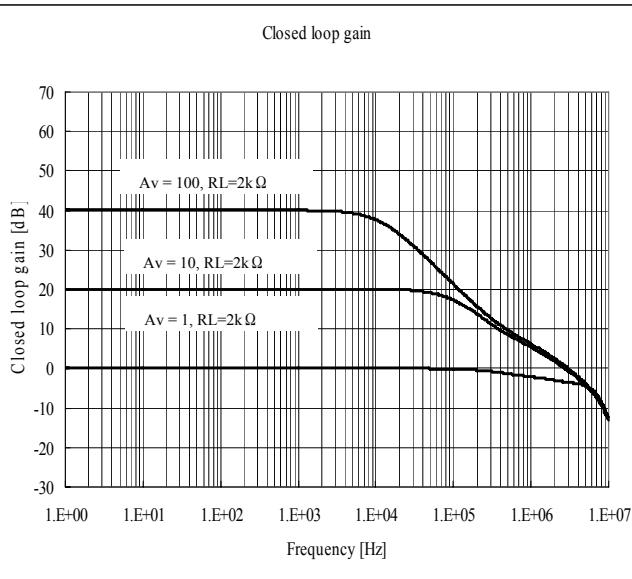
□ Output voltage vs. Load current  
(VDD=5V, Ta=25°C)



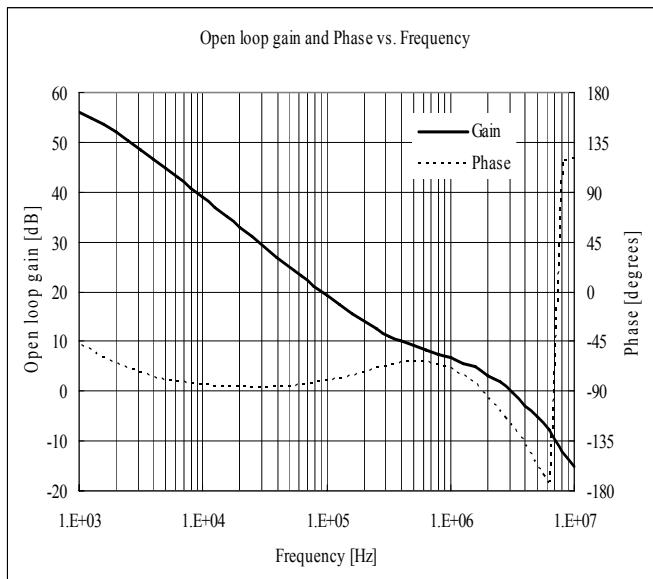
□ Closed loop gain vs. Frequency  
(VDD=1.6V, Ta=25°C)



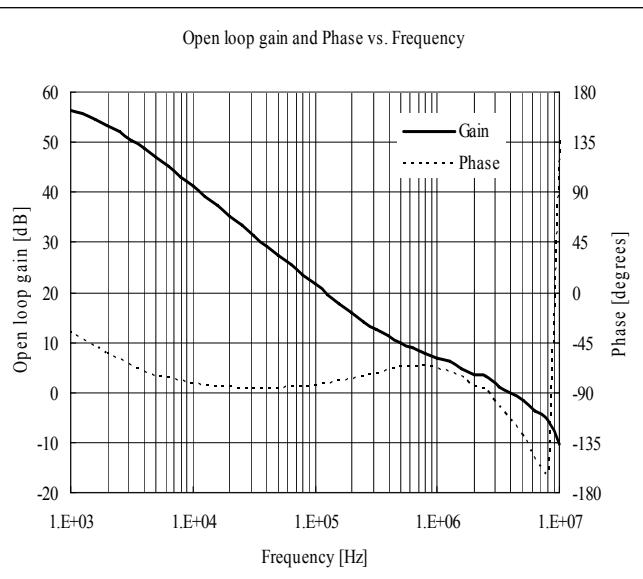
□ Closed loop gain vs. Frequency  
(VDD=5V, Ta=25°C)



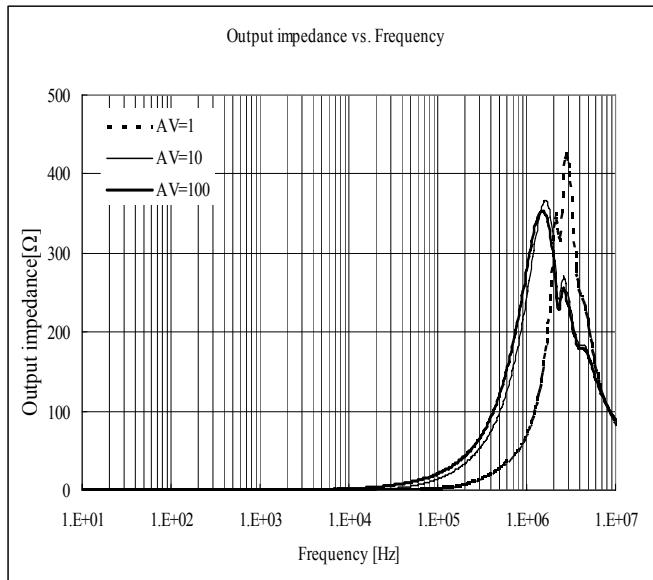
□ Open loop gain and Phase vs. Frequency  
(VDD=1.6V, Ta=25°C)



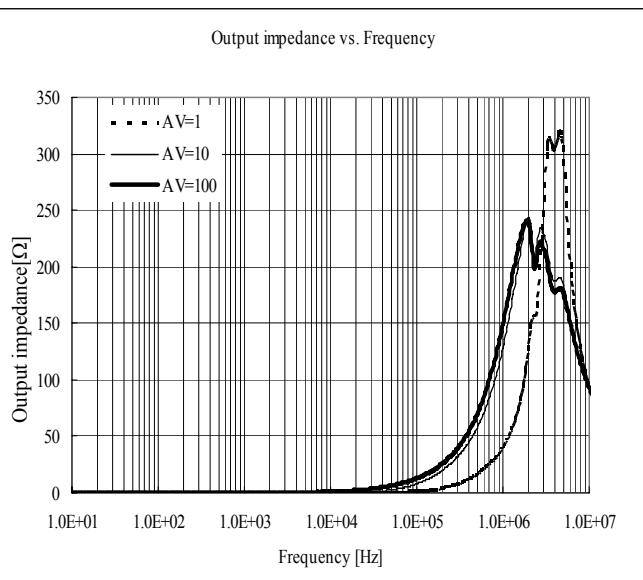
□ Open loop gain and Phase vs. Frequency  
(VDD=5V, Ta=25°C)



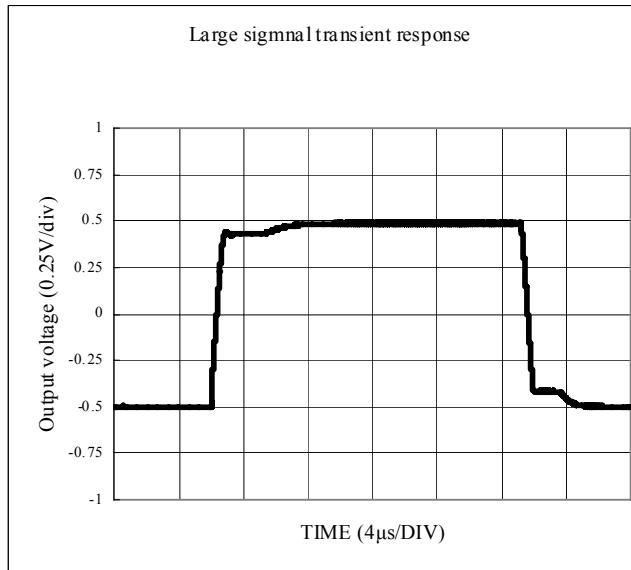
□ Output impedance vs. Frequency  
(VDD=1.6V, Ta=25°C)



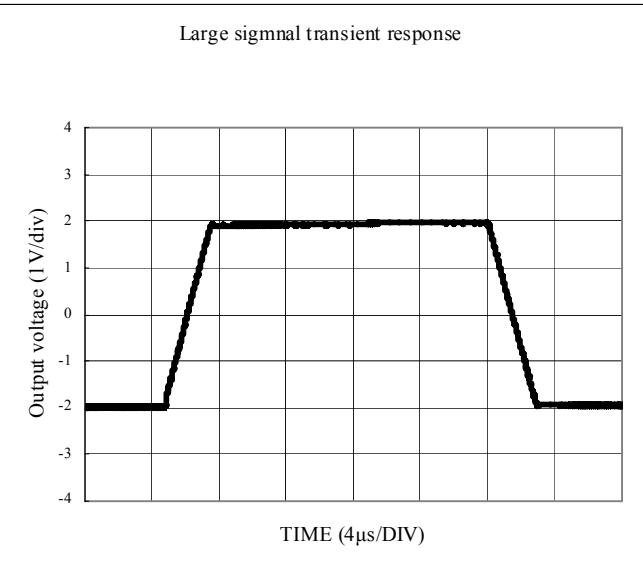
□ Output impedance vs. Frequency  
(VDD=5V, Ta=25°C)



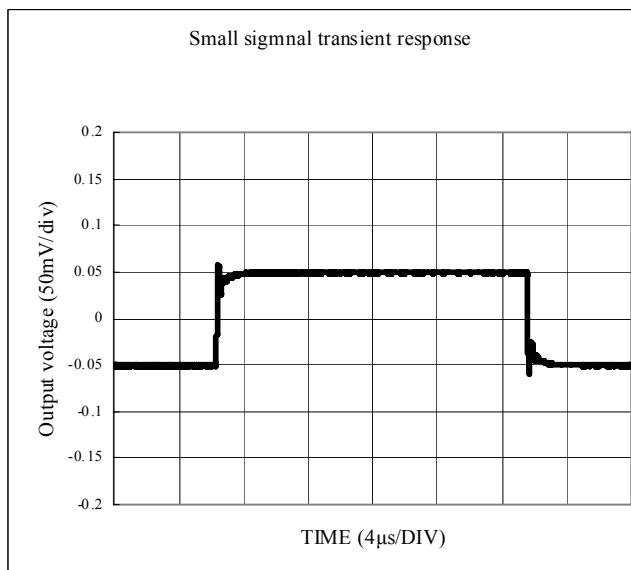
- Large signal transient response  
(VDD/VSS = +0.8V/- 0.8V,  
Ta = 25°C, CL = 150pF)



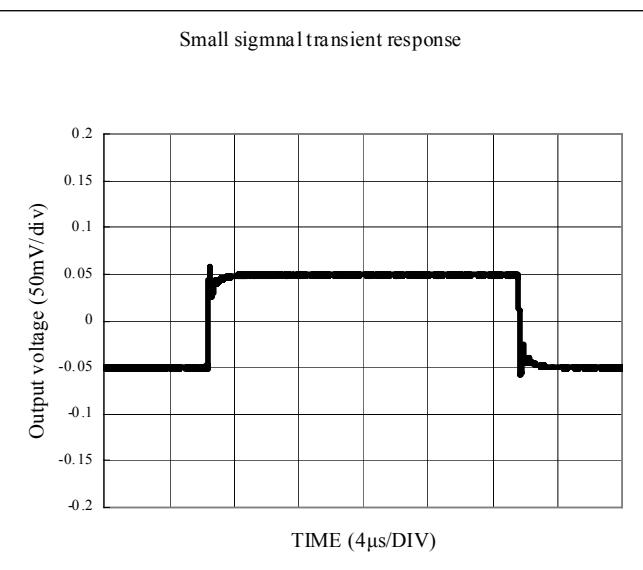
- Large signal transient response  
(VDD/VSS = +2.5V/-2.5V  
Ta = 25°C, CL = 150pF)



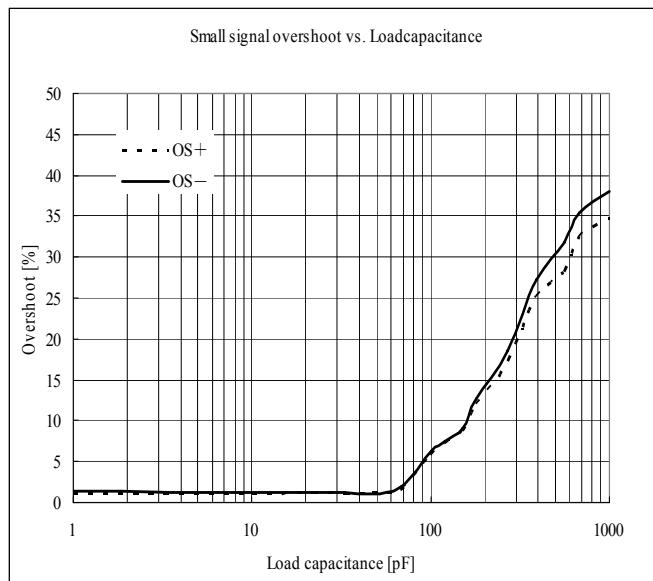
- Small signal transient response  
(VDD/VSS = +0.8V/- 0.8V,  
Ta = 25°C, CL = 150pF)



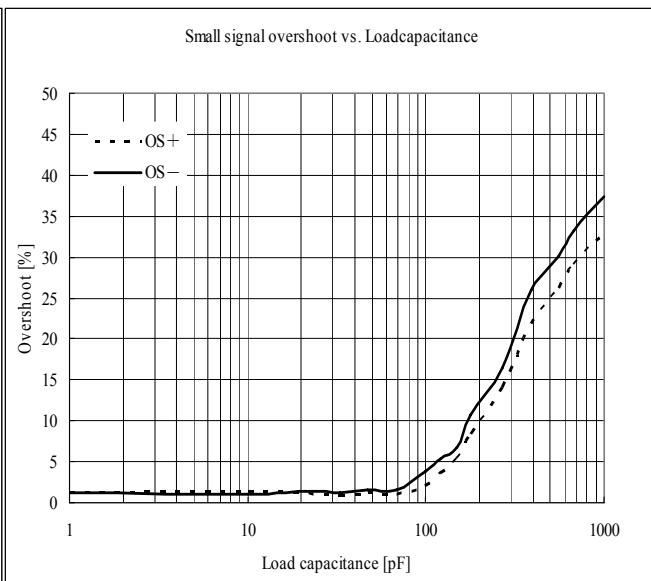
- Small signal transient response  
(VDD/VSS = +2.5V/-2.5V  
Ta = 25°C, CL = 150pF)



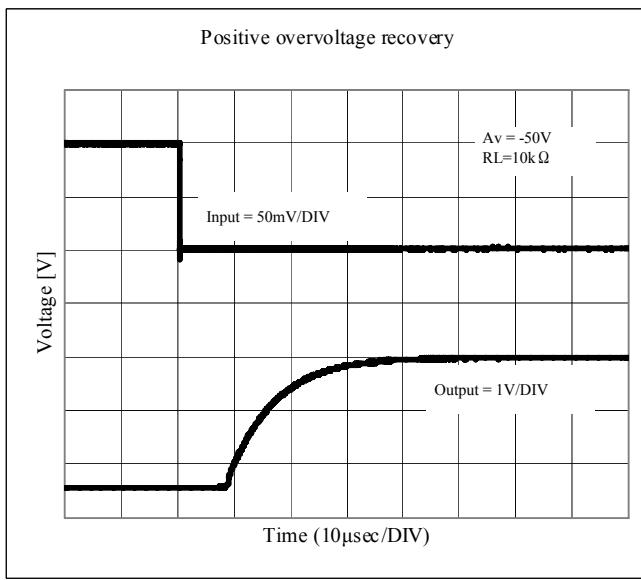
Small signal overshoot vs. Load Capacitance  
(VDD=1.6V, Ta=25°C)



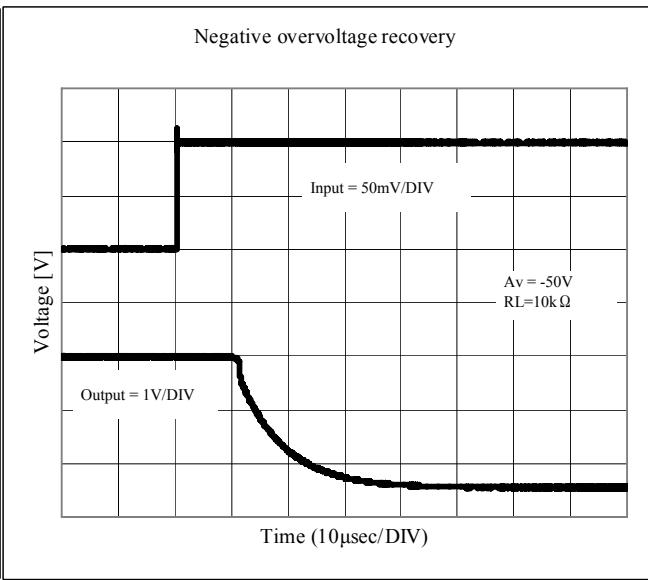
Small signal overshoot vs. Load Capacitance  
(VDD=5V, Ta=25°C)

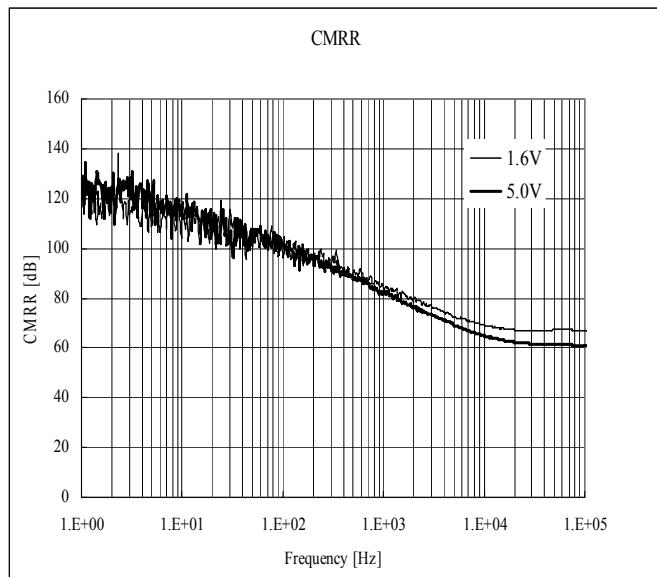
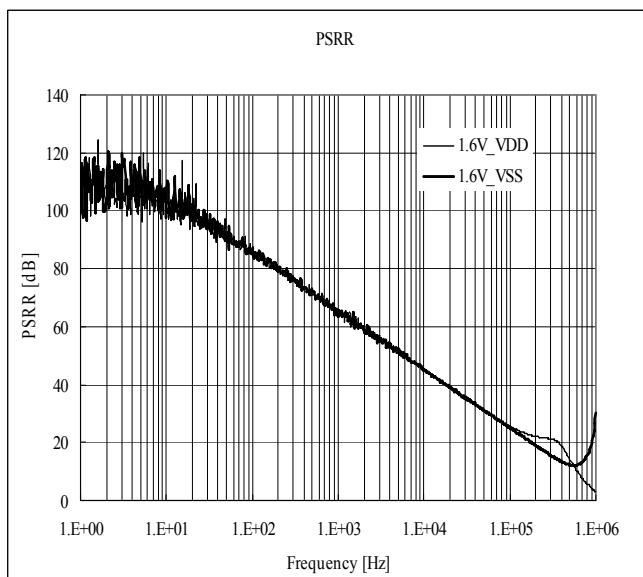
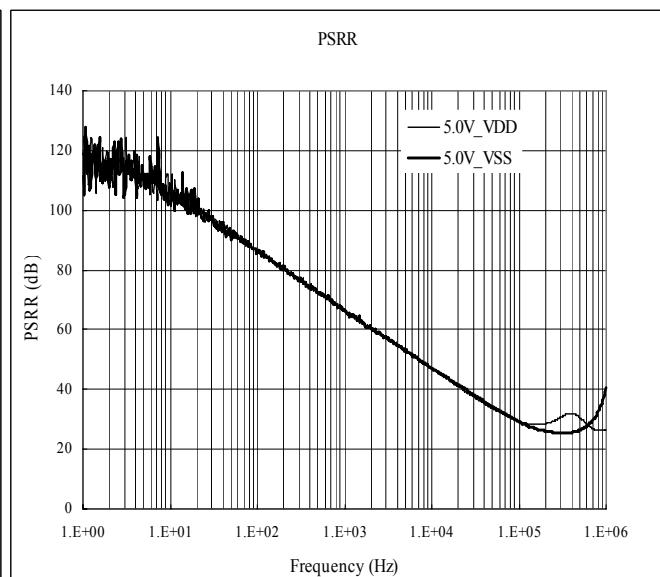


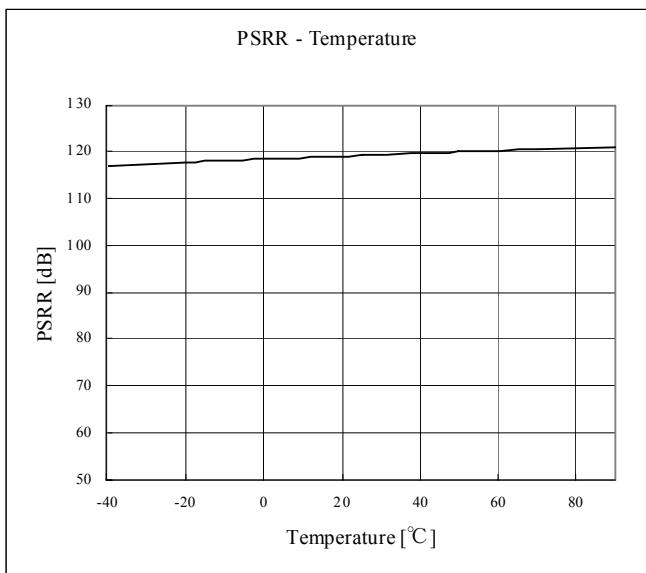
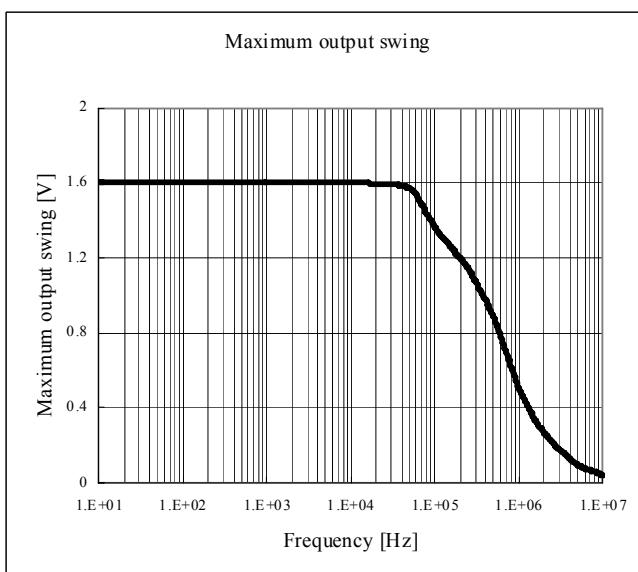
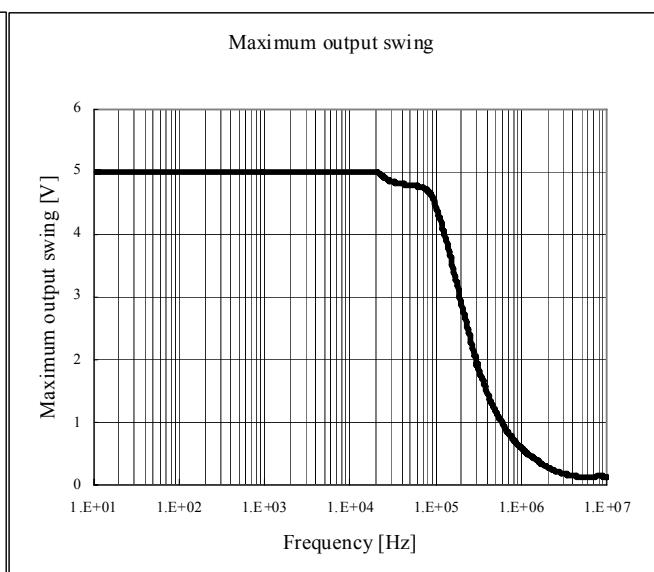
Positive overvoltage recovery  
(VDD/VSS = +2.5V/-2.5V, Ta = 25°C)



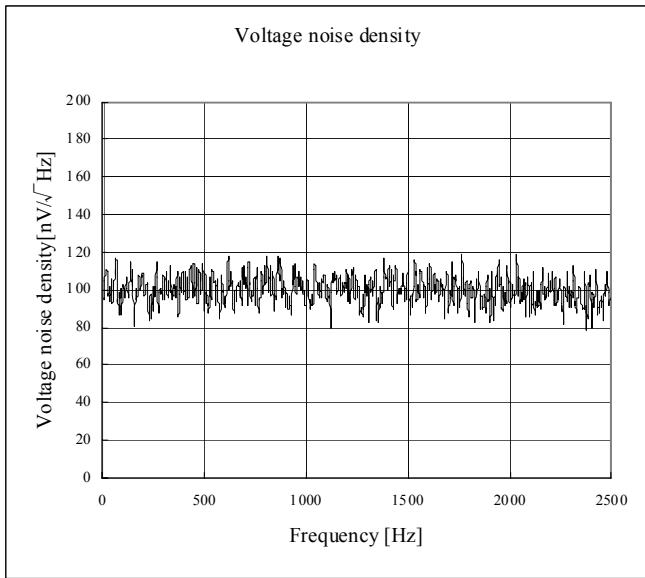
Negative overvoltage recovery  
(VDD/VSS = +2.5V/-2.5V, Ta = 25°C)



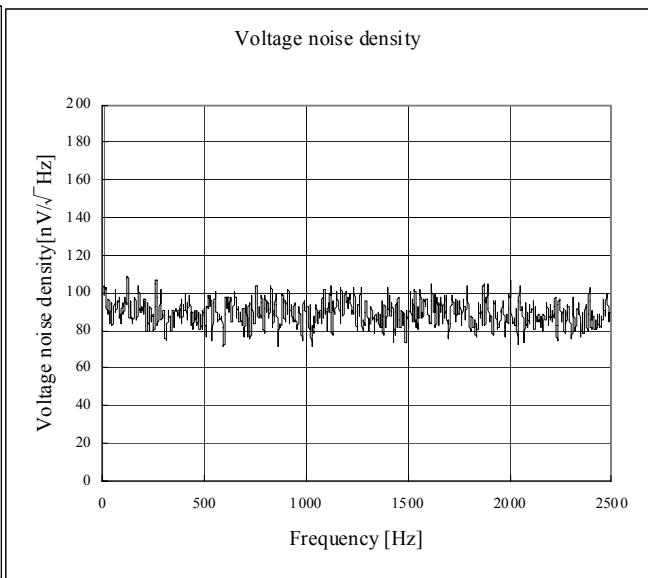
Common Mode Rejection Ratio vs. Frequency Power Supply Rejection Ratio vs. Frequency  
(VDD=1.6V, Ta=25°C) Power Supply Rejection Ratio vs. Frequency  
(VDD=5V, Ta=25°C)

Power Supply Rejection Ratio vs. Temperature Maximum output swing vs. Frequency  
(VDD=1.6V, Ta=25°C, Av = 1, RL = 10kΩ) Maximum output swing vs. Frequency  
(VDD=5V, Ta=25°C, Av = 1, RL = 10kΩ)

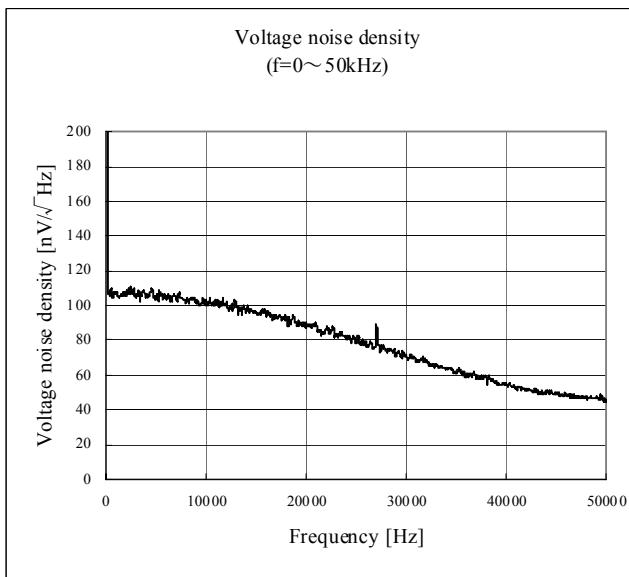
Voltage noise density  
(VDD=1.6V, Ta=25°C, f=0~2.5kHz)



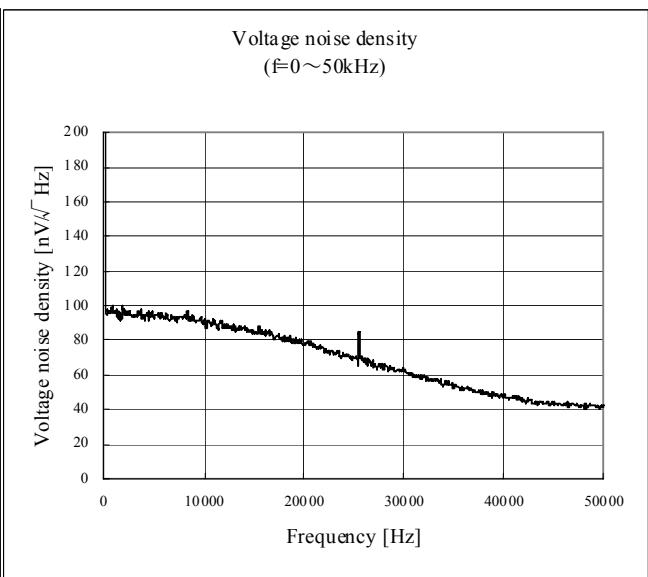
Voltage noise density  
(VDD=5V, Ta=25°C, f=0~2.5kHz)



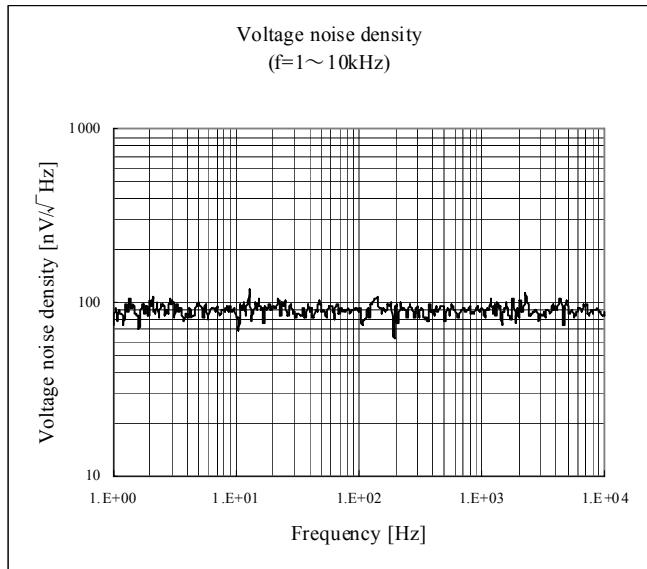
Voltage noise density  
(VDD=1.6V, Ta=25°C, f=0~20kHz)



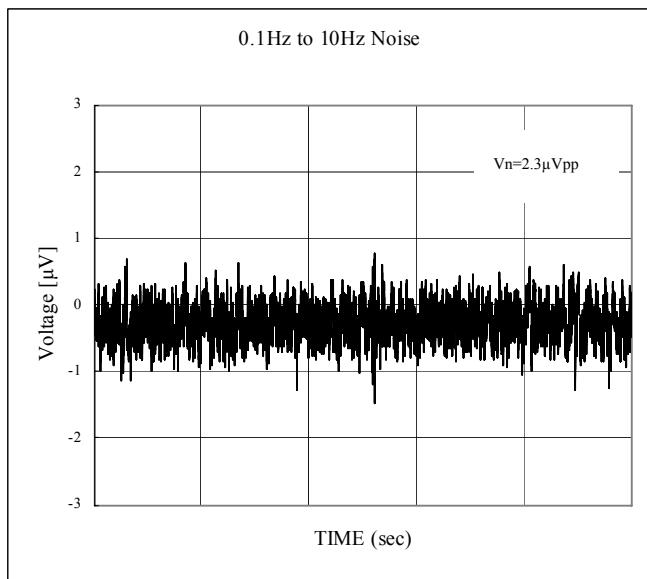
Voltage noise density  
(VDD=5V, Ta=25°C, f=0~50kHz)



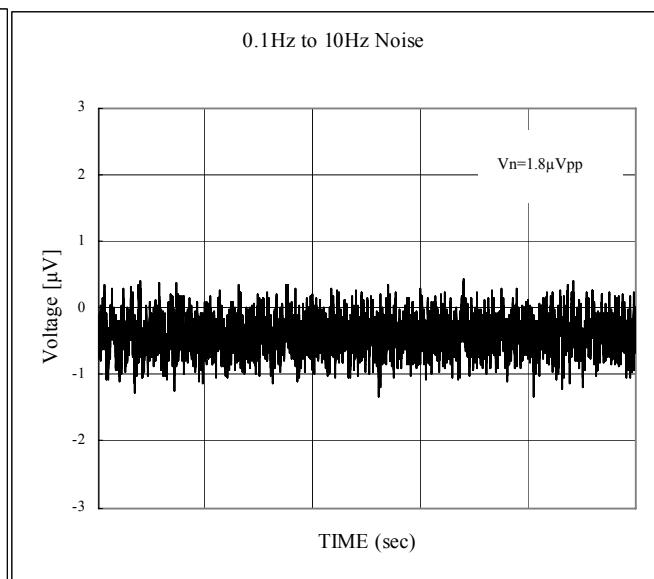
- Voltage noise density  
(VDD=5V, Ta=25°C, f=1~10kHz)



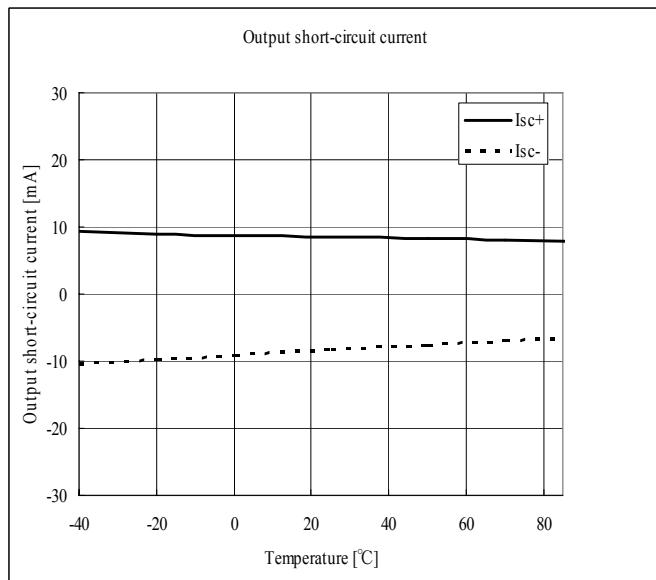
- Voltage noise  
(VDD=1.6V, Ta=25°C, f=0.1~10Hz)



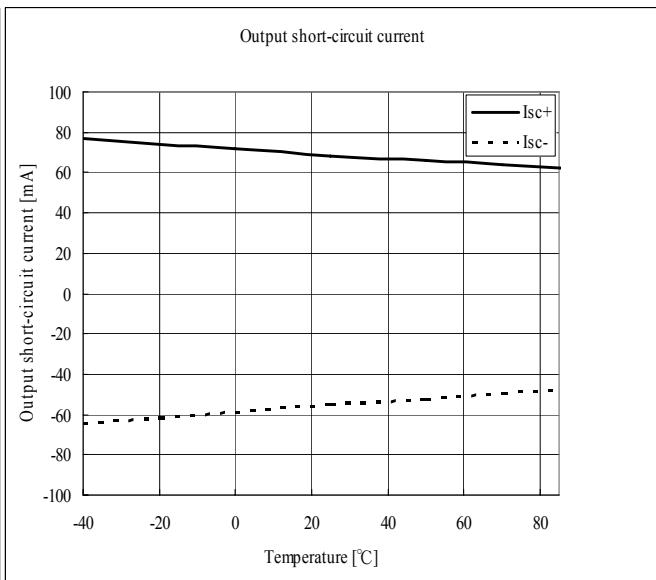
- Voltage noise  
(VDD=5V, Ta=25°C, f=0.1~10Hz)



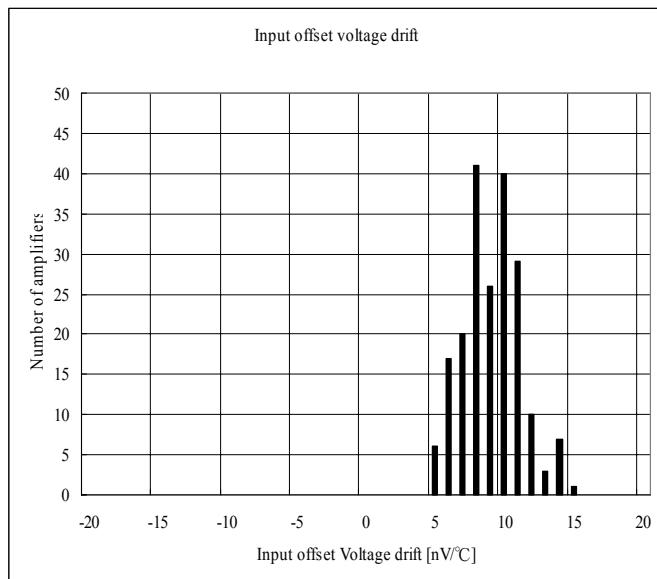
Output short-circuit current vs. Temperature  
(VDD=1.6V, Ta=-40 to 85°C)



Maximum output swing vs. Frequency  
(VDD=5V, Ta=25°C, Ta=-40 to 85°C)



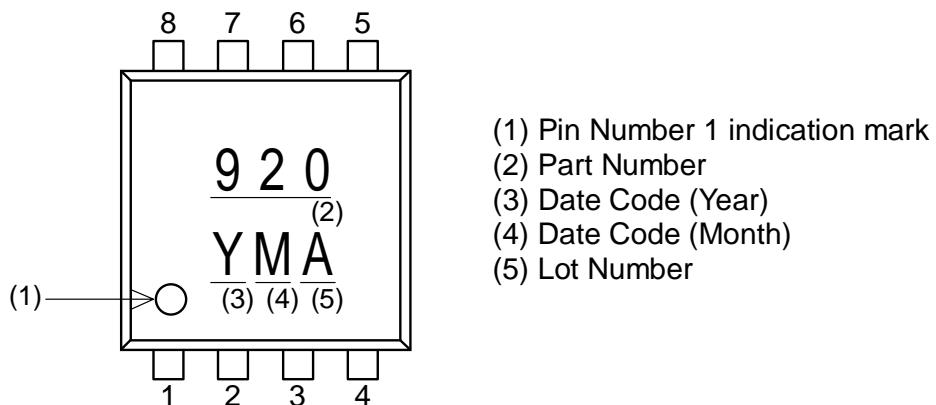
Input offset voltage drift(VDD=5V, Ta=25°C, Ta=-40 to 85°C)



**Package**

## 1. Marking

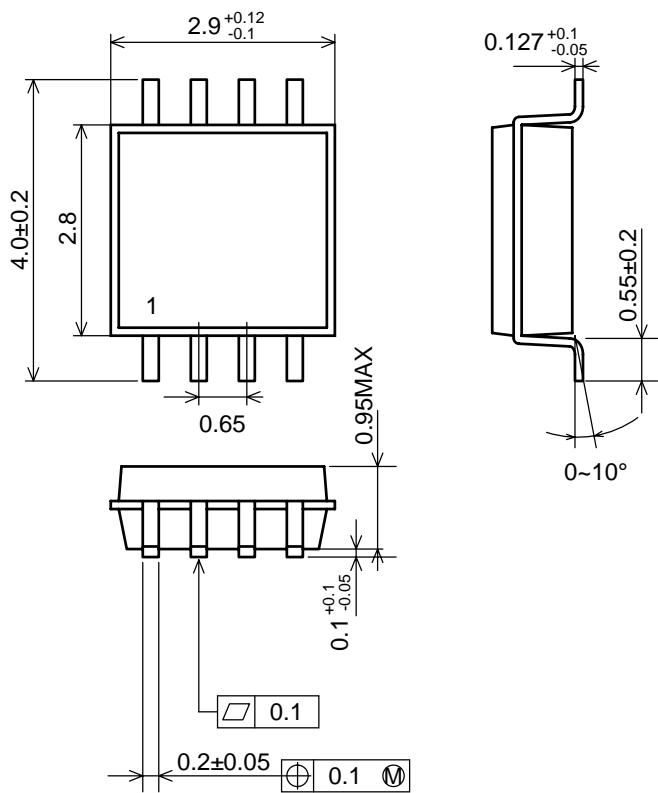
## 1.1 TMSOP8



## 2. Outline Dimensions

## 2.1 TMSOP8 Package Outline

(UNIT:mm)



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